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**Nathan et al.**

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(54) **PIXEL DRIVER CIRCUIT WITH  
LOAD-BALANCE IN CURRENT MIRROR  
CIRCUIT**

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See application file for complete search history.

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(57) **ABSTRACT**

A pixel circuit for use in a display comprising a plurality of pixels is provided. The load-balanced current mirror pixel circuit can compensate for device degradation and/or mismatch, and changing environmental factors like temperature and mechanical strain. The pixel circuit comprises a pixel drive circuit comprising, switching circuitry, a current mirror having a reference transistor and a drive transistor, the reference transistor and the drive transistor each having a first and second node and a gate, the gate of the reference transistor being connected to the gate of the drive transistor; and a capacitor connected between the gate of the reference transistor and a ground potential, and a load connected between the current mirror and a ground potential, the load having a first load element and a second load element, the first load element being connected to the first node of the reference transistor and the second load element being connected to the first node of the drive transistor.

**13 Claims, 15 Drawing Sheets**

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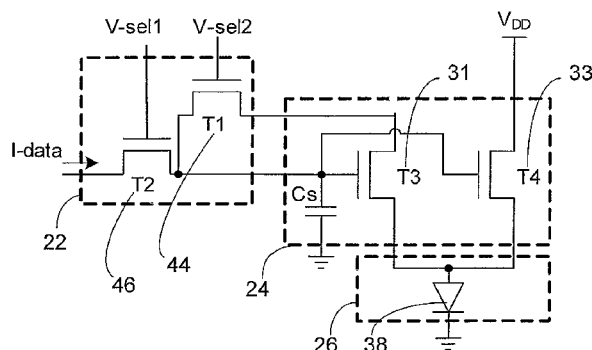
**H05B 37/02** (2006.01)

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**2300/0842** (2013.01)

(58) **Field of Classification Search**

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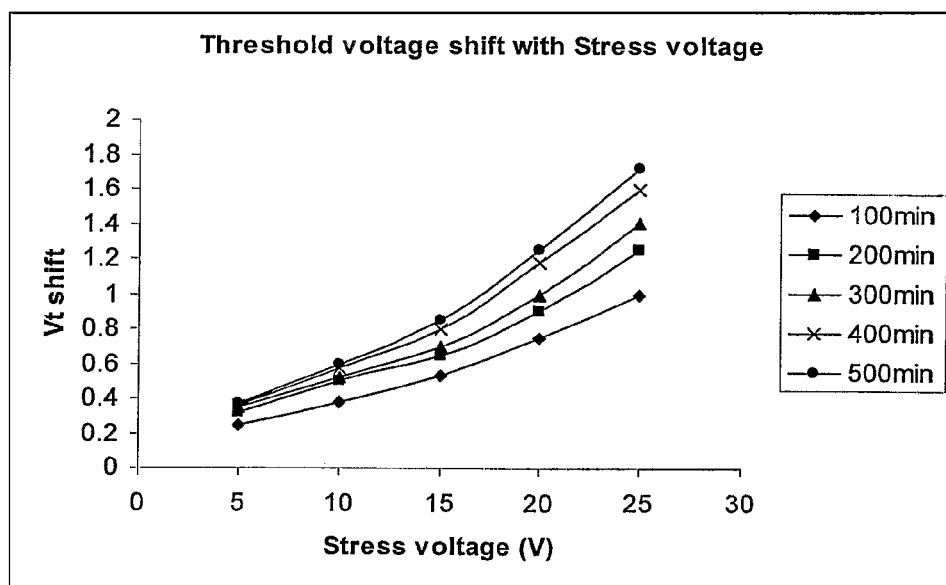
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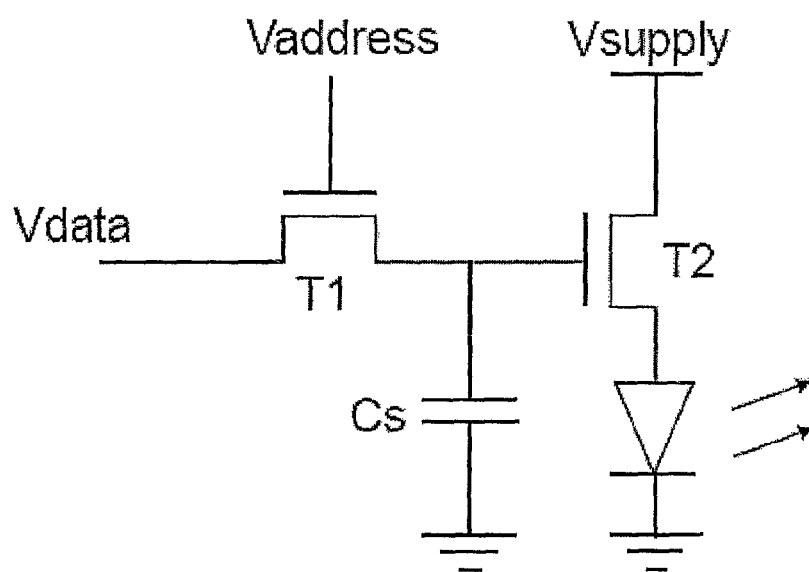
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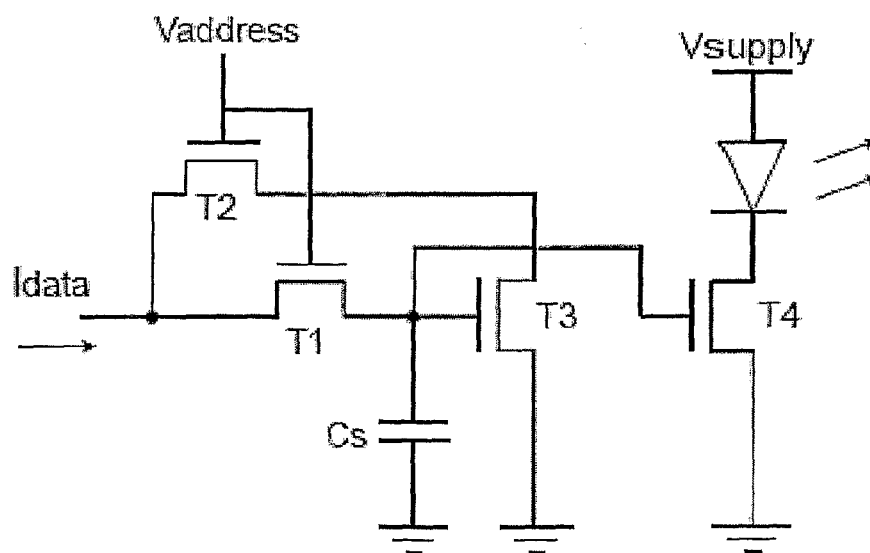




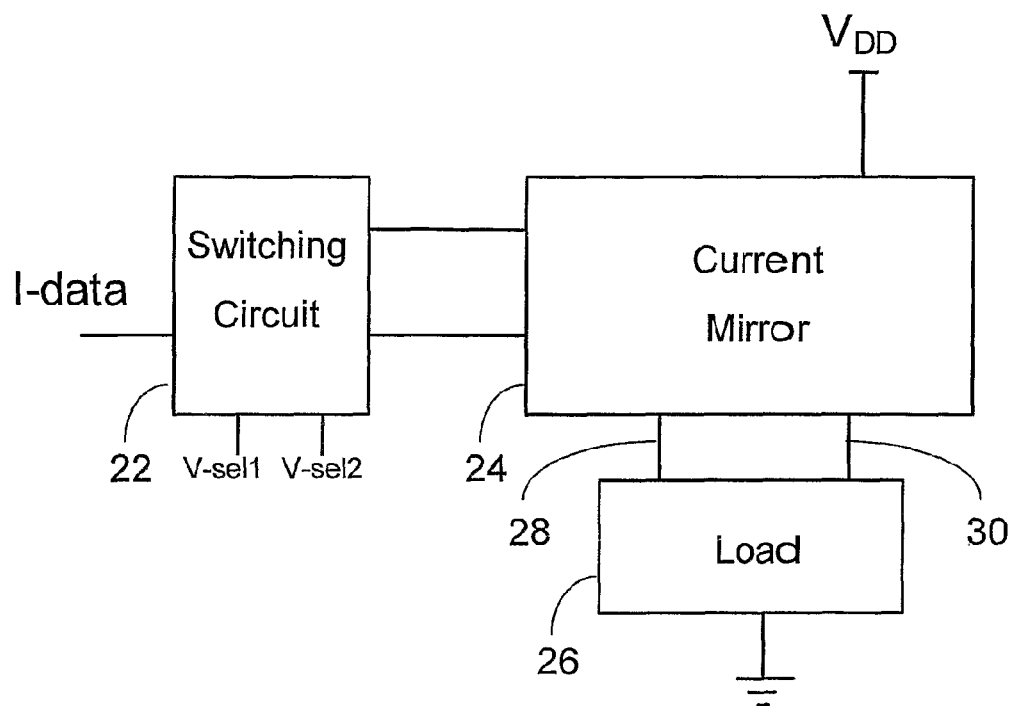
*Figure 1 (PRIOR ART)*

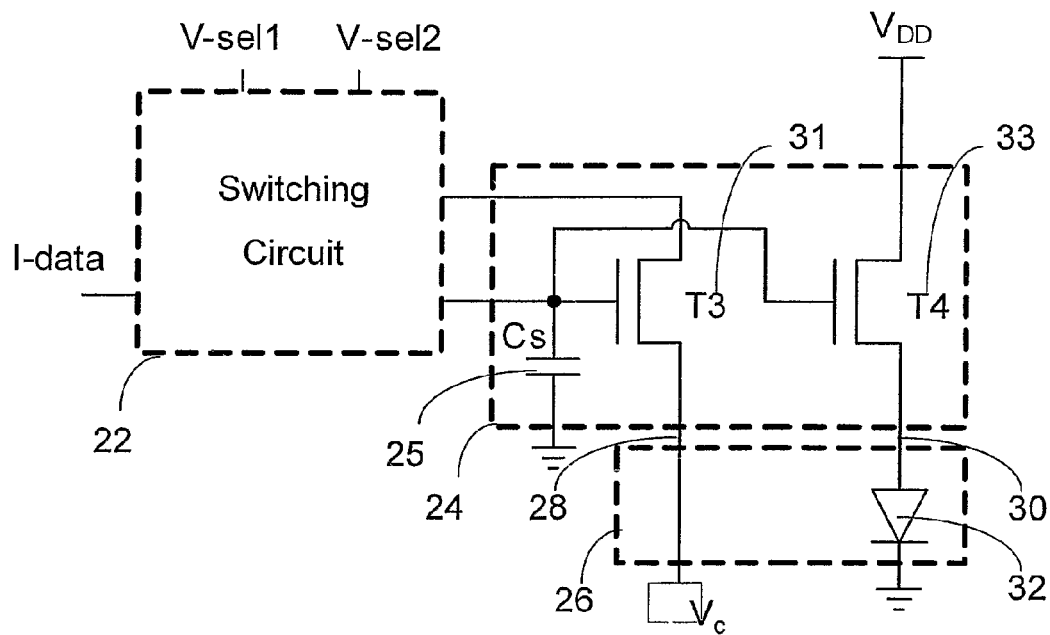


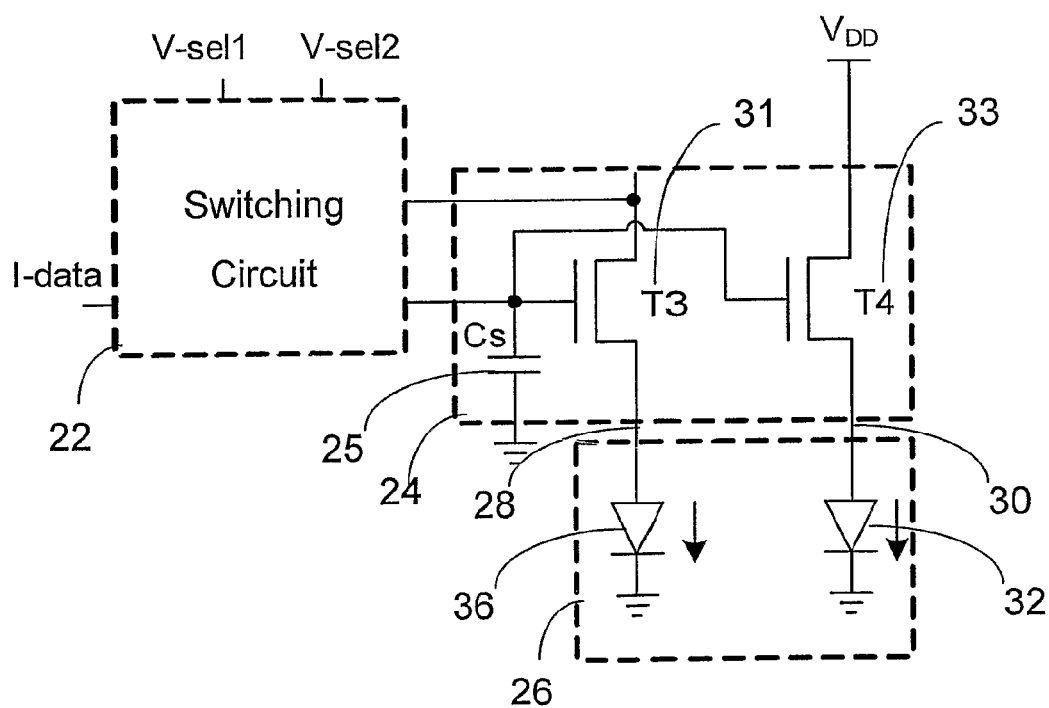
*Figure 2 (PRIOR ART)*



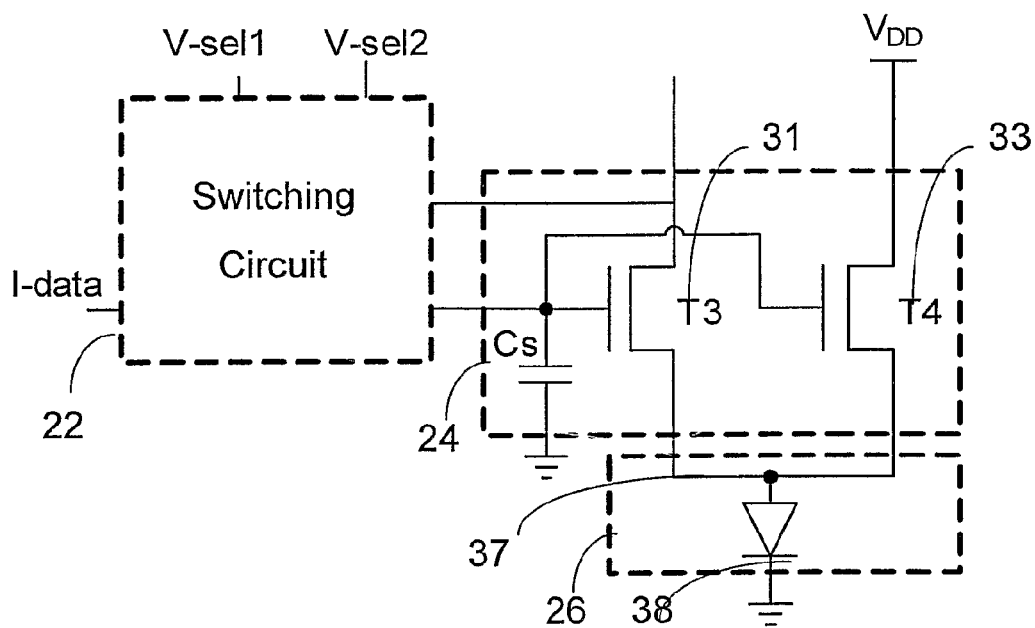
*Figure 3 (PRIOR ART)*

*Figure 4*

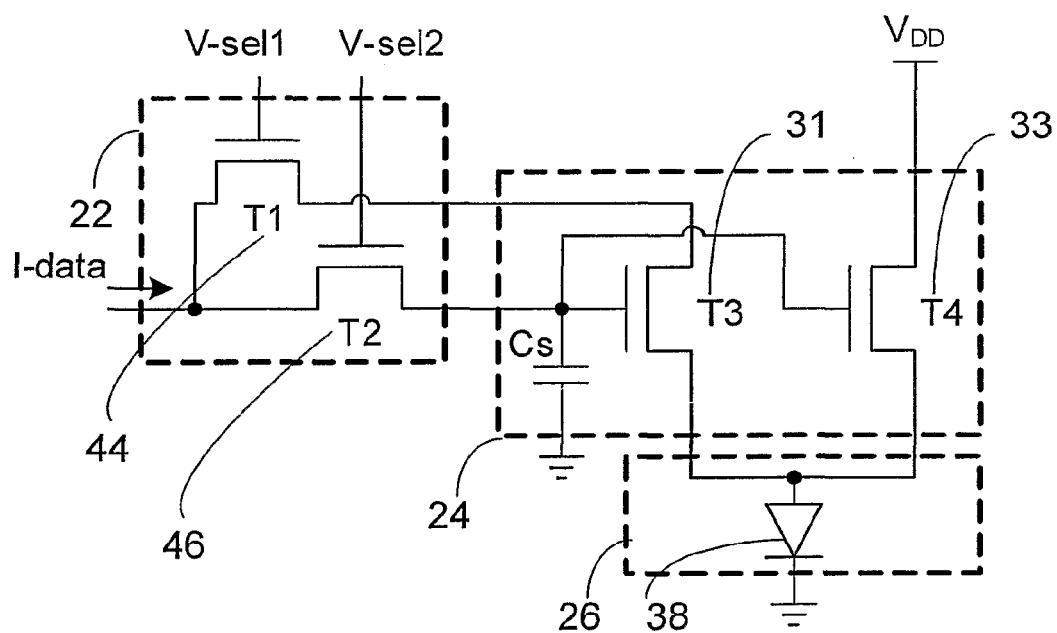
*Figure 5A*



**Figure 5B**

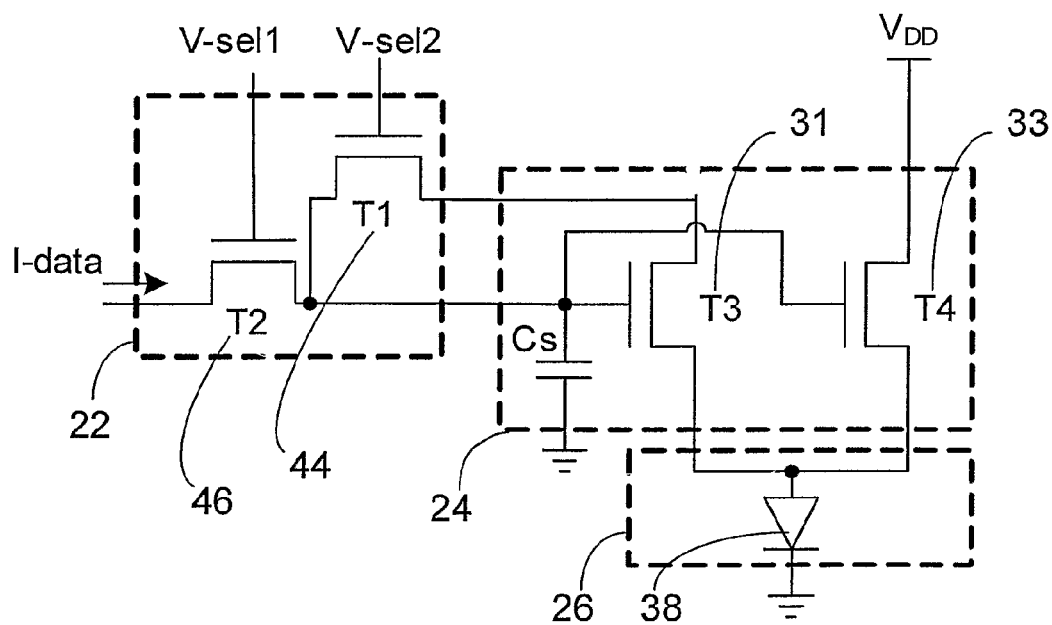


*Figure 5C*



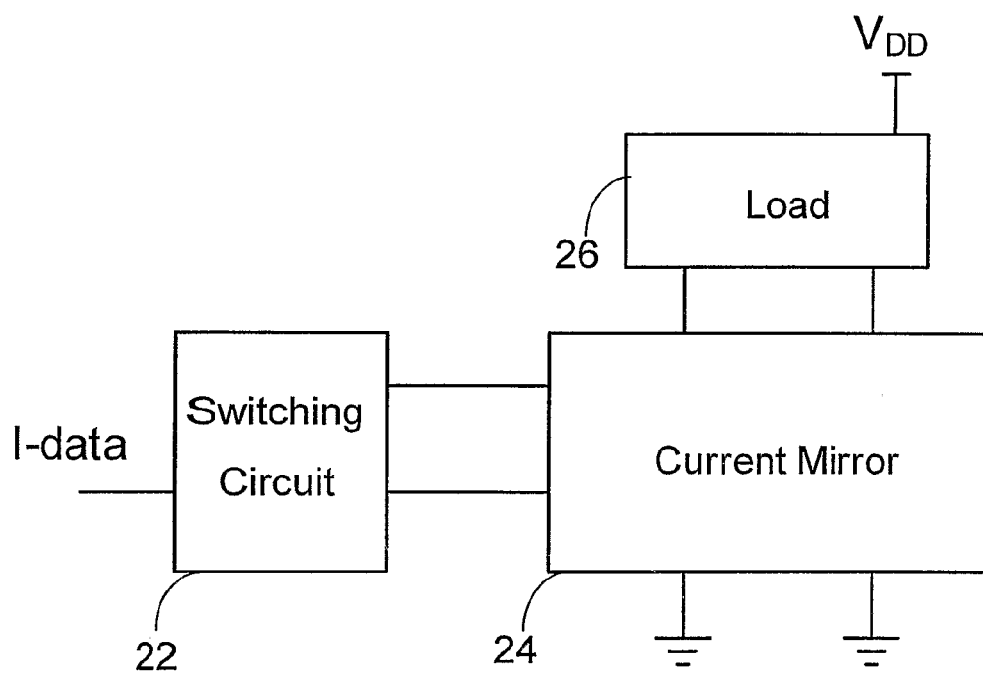
*Figure 6A*

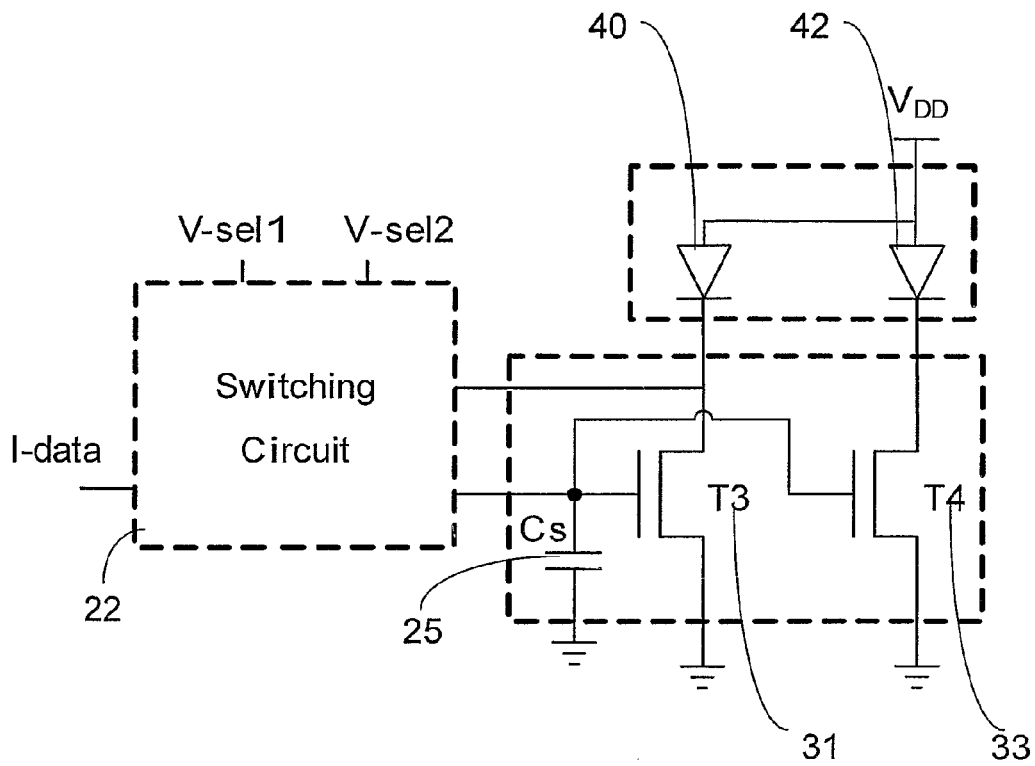


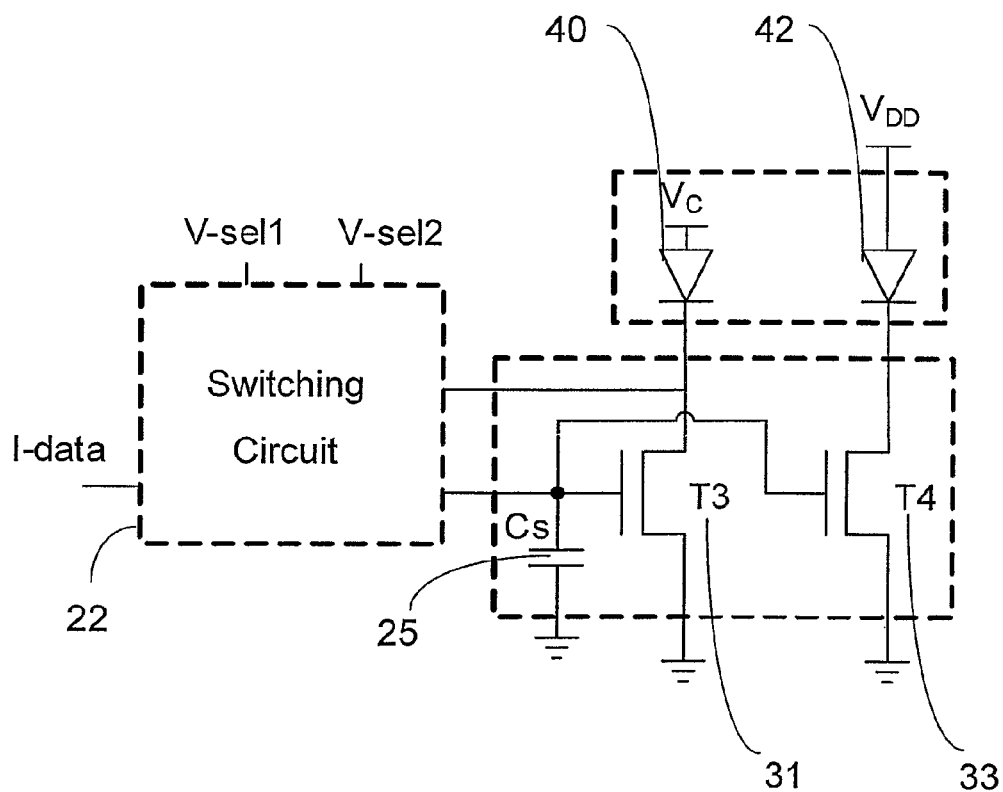


*Figure 6B*

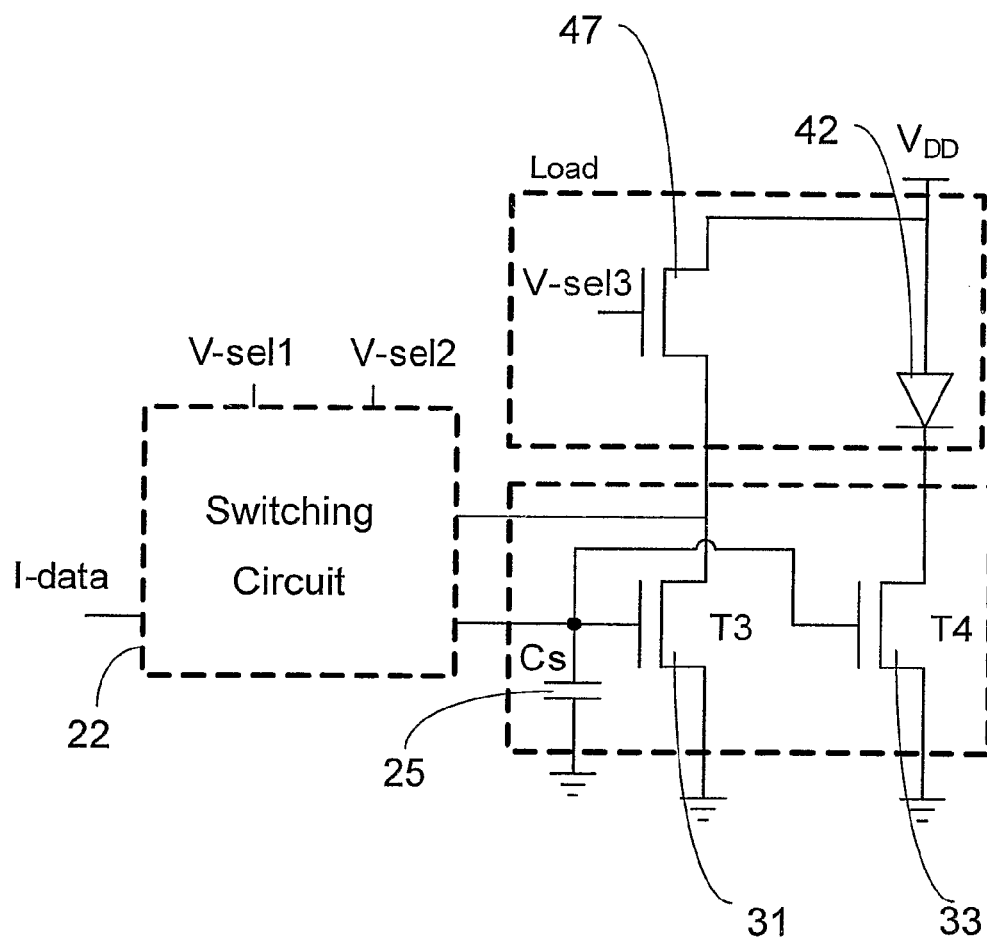
**Figure 6C**

*Figure 7A*

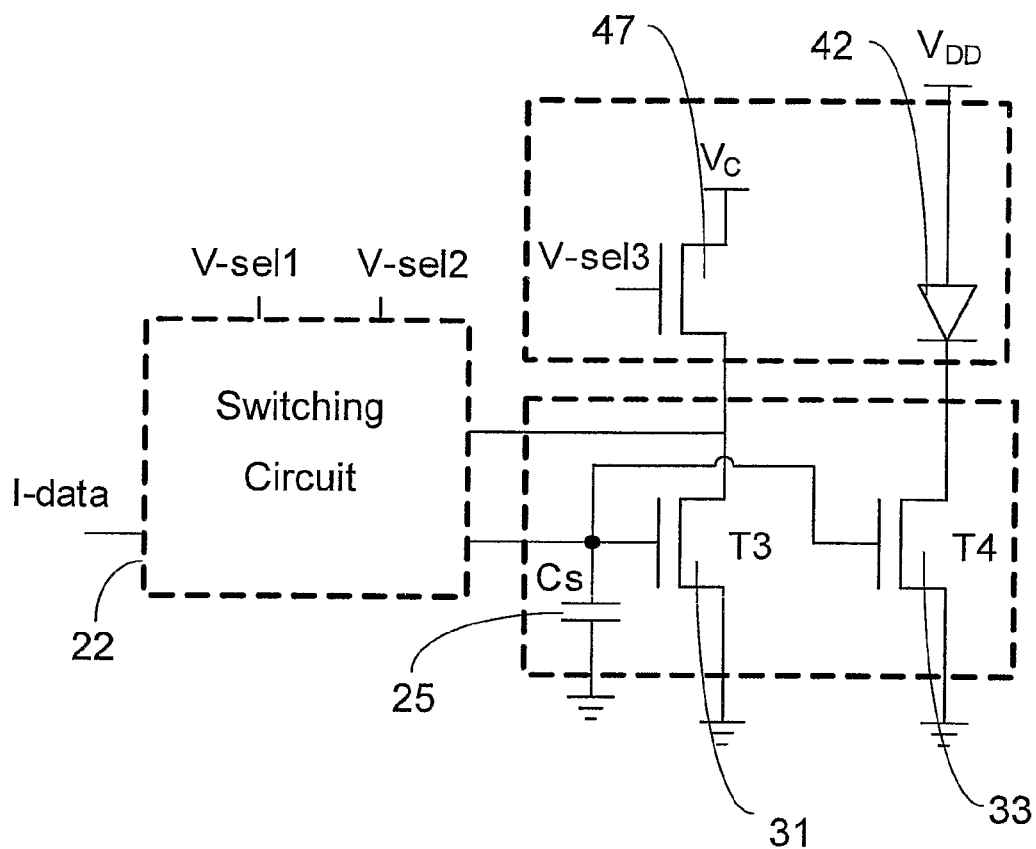
*Figure 7B*



*Figure 7C*



**Figure 7D**

*Figure 7E*

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# PIXEL DRIVER CIRCUIT WITH LOAD-BALANCE IN CURRENT MIRROR CIRCUIT

## CROSS REFERENCE TO RELATED APPLICATIONS

This application is a continuation of pending U.S. application Ser. No. 10/554,795, filed Jun. 15, 2006, now allowed, which is a U.S. National Stage of International Application No. PCT/CA2004/001741, filed Sep. 23, 2004, which claims the benefit of Canadian Patent Application No. 2,443,206, filed Sep. 23, 2003, all of which are incorporated herein by reference in their entireties.

## FIELD OF INVENTION

### Background of the Invention

OLED based displays have gained significant interest recently for many display applications because of their faster response times, larger viewing angles, higher contrast, lighter weight, lower power, and amenability to flexible substrates, as compared to liquid crystal displays (LCDs).

The simplest way of addressing an OLED display is to use a passive matrix format. Although passive matrix addressed OLED displays are already in the marketplace, they do not support the resolution needed for next generation displays, which use high information content (HIC) formats. HIC formats are only possible with an active matrix addressing scheme.

Active matrix addressing involves a layer of backplane electronics, based on thin-film transistors (TFTs). These thin film transistors provide the bias voltage and drive current needed in each OLED pixel and may be fabricated using amorphous silicon (a-Si:H), polycrystalline silicon (poly-Si), organic, polymer, or other transistor technologies. When compared to passive matrix addressing, active matrix addressing uses a lower voltage on each pixel and the current throughout the entire frame period is a low constant value. Thus, active matrix addressing avoids the excessive peak driving and leakage currents associated with passive matrix addressing. This increases the lifetime of the OLED.

LCDs are electric field driven devices. OLEDs, on the other hand, are current driven devices. Thus, the brightness and stability of the light emitted by a given OLED used in a display is dependent on the operation of the TFTs in the current drive circuit. Thus AMOLED displays are far more sensitive to TFT instabilities including, spatial and temporal variations in transistor threshold voltage, mobility instability, and mismatch issues. These instabilities need to be addressed for widespread use of OLED based displays.

FIG. 1 presents a graph of threshold voltage shift vs. stress voltage for various times for amorphous silicon based TFTs. It is readily apparent from FIG. 1 that the threshold voltage of the transistors varies over time. If these transistors were used in a display, the variation in threshold voltage would likely result in variation in the brightness of the OLED across the array and/or a decrease in brightness over time, both of which are unacceptable.

A simple pixel driver circuit is shown in FIG. 2. This "2T" circuit is a voltage programmed circuit. Such a circuit is not practical for OLED displays as such a circuit cannot compensate for variations in transistor threshold voltage. One solution to this variation in threshold voltage is to use a current programmed circuit to drive the OLED of the pixels. Current programming is a good method for driving AMO-

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LED displays since the OLED is a current driven device, and its brightness is approximately linearly dependent upon the current flowing through it.

One such current programmed circuit is presented in FIG. 3. This circuit incorporates a current-mirror which compensates for any shift or mismatch in the threshold voltage of the drive transistor T4 which ensures that the brightness of the OLED does not decrease over time. This feature of the circuit allows its drive characteristics to be much improved as compared to the 2T circuit of FIG. 2.

When programming the circuit of FIG. 3,  $V_{ADDRESS}$  is high and a current  $I_{DATA}$  is applied. This current initially flows through transistor T1 and charges capacitor  $C_s$ . As the capacitor voltage rises, T3 begins to turn on and  $I_{DATA}$  starts to flow through T2 and T3 to ground. The capacitor voltage stabilizes at the point when all of  $I_{DATA}$  flows through T2 and T3, and none through T1. This process is independent of the threshold voltage  $V_T$  of transistors T3 and T4.

The gates of T3 and T4 are connected, so the current flowing through T3 is mirrored in T4. This topology allows us to have on-pixel current gain or attenuation depending on the sizing of T3 and T4, so that the respective data current can be proportionately smaller or larger than the OLED current. In an active matrix array, pixels are scanned and programmed in a row-by-row fashion. The time taken to scan all rows (one frame) is called the frame time. During array operation, the switching TFTs (T1 and T2) are ON only once in the frame time.

However, existing current programmed circuits do not adequately address long-term stability in the OLED drive current due to differential  $V_t$ -shift and other bias, temperature, or mechanical stress related degradations and mismatches in the current mirror.

## SUMMARY OF THE INVENTION

The present invention relates to a circuit for driving light emitting elements in a display and more particularly relates to a current drive circuit that implements a current mirror wherein each transistor of the current mirror is connected to a load.

It is an object of the invention to provide improved AMOLED Display Backplanes and Pixel Driver Circuits.

Accordingly, it is an object of the present invention to provide pixel current driver circuits for active matrix organic light emitting displays (AMOLED), capable of providing stable and predictable drive currents, in the presence of device degradation and/or mismatch, and changing environmental factors like temperature and mechanical strain. The latter is particularly important for mechanically flexible AMOLED displays.

According to an aspect of the invention a pixel circuit for use in a display comprising a plurality of pixels is provided. The pixel circuit comprises a pixel drive circuit comprising, switching circuitry, a current mirror having a reference transistor and a drive transistor, the reference transistor and the drive transistor each having a first and second node and a gate, the gate of the reference transistor being connected to the gate of the drive transistor; and a capacitor connected between the gate of the reference transistor and a ground potential, and a load connected between the current mirror and a ground potential, the load having a first load element and a second load element, the first load element being connected to the first node of the reference transistor and the second load element being connected to the first node of the drive transistor.



According to another aspect of the invention a pixel circuit for use in a display comprising a plurality of pixels is provided. The pixel circuit comprises a pixel drive circuit comprising, switching circuitry, a current mirror having a reference transistor and a drive transistor, the reference transistor and the drive transistor each having a first and second node and a gate, the gate of the reference transistor being connected to the gate of the drive transistor, the second node of the reference and drive transistors connected to a ground potential, and a capacitor connected between the gate of the reference transistor and a ground potential, and a load connected between the current mirror and a potential.

This summary of the invention does not necessarily describe all features of the invention.

### BRIEF DESCRIPTION OF THE DRAWINGS

These and other features of the invention will become more apparent from the following description in which reference is made to the appended drawings wherein:

FIG. 1 shows a graph of threshold voltage shift v. gate stress voltage for various times for thin film transistors made from amorphous silicon;

FIG. 2 shows a schematic diagram of a 2T voltage-programmed pixel driver circuit;

FIG. 3 shows a schematic diagram of a 4T current-programmed driver circuit;

FIG. 4 shows a block diagram of a current-programmed driver circuit according to an embodiment of the invention;

FIG. 5A shows a schematic diagram of a current-programmed driver circuit according to an embodiment of the invention;

FIG. 5B shows a schematic diagram of a current-programmed driver circuit according to an embodiment of the invention;

FIG. 5C shows a schematic diagram of a current-programmed driver circuit according to an embodiment of the invention;

FIG. 6A shows a schematic diagram of a current-programmed driver circuit according to an embodiment of the invention;

FIG. 6B shows a schematic diagram of a current-programmed driver circuit according to an embodiment of the invention;

FIG. 6C shows a schematic diagram of a current-programmed driver circuit according to an embodiment of the invention;

FIG. 7A shows a block diagram of a current-programmed driver circuit according to an embodiment of the invention;

FIG. 7B shows a schematic diagram of a current-programmed driver circuit according to an embodiment of the invention;

FIG. 7C shows a schematic diagram of a current-programmed driver circuit according to an embodiment of the invention;

FIG. 7D shows a schematic diagram of a current-programmed driver circuit according to an embodiment of the invention; and

FIG. 7E shows a schematic diagram of a current-programmed driver circuit according to an embodiment of the invention.

The above objects and features of the present invention will become more apparent by the following description of the preferred embodiments with reference to the attached drawings.

### DETAILED DESCRIPTION

It has been found that the long-term stability of the OLED drive current can be addressed by providing a load to each transistor of the current mirror of a current based drive circuit.

A block diagram of a pixel driver circuit according to one aspect of the invention is shown in FIG. 4. The driver circuit can generally be considered to include a switching circuit 22, a current mirror 24 and a load 26. Of particular note is that the load 26 is configured, with respect to the current mirror 24, such that the two transistors of the current mirror 24 have a load connected to them. In the configuration shown in FIG. 4 the load 26 is connected between the current mirror 24 and ground with connections 28 and 30. Where the connections 28 and 30 are each connected to a node of a transistor of the current mirror and the load 26. This architecture provides for a balancing of the load between the transistors of the current mirror. Embodiments of the invention that implement this architecture will now be presented.

In the embodiment presented in FIG. 4 the switching circuit 22 is connected to two select lines, namely V-sel1 and V-sel2. The embodiments presented in FIGS. 5A-5C, 6A-6C and 7A-7E likewise have two select lines. The switching circuit 22 is further connected to a single data line, I-data.

The circuits presented in FIGS. 5A to 5C have the same basic architecture as the circuit presented in FIG. 4, i.e. both transistors of the current mirror are connected to the load 26. The circuits of FIGS. 5A to 5C present type and configuration variations for the load 26.

In FIG. 5A the current mirror 24 includes a reference transistor 31, a drive transistor 33. The transistors 31 and 33 are thin film transistors which have an amorphous silicon channel. A storage capacitor 25 is included in the current mirror 24. The gates of the transistor 31 and the transistor 33 are tied together and both connected to a plate of the storage capacitor 25. The other plate of the storage capacitor Cs is connected to ground. The source of the reference transistor 31 is connected to potential Vc and the drain is connected to the switching circuit 22. Connecting the source to the potential Vc allows the two sides of the current mirror to be balanced with proper biasing. The source of the drive transistor 33 is connected to a light emitting diode 32 and the drain is connected to V<sub>DD</sub>. In this embodiment the light emitting diode 32 is an organic light emitting diode (OLED).

FIG. 5B is a schematic diagram of a pixel driver circuit according to another embodiment of the invention. In this embodiment the source of the reference transistor 31 and the drive transistor 33 are connected to light emitting diodes 36 and 32, respectively.

FIG. 5C presents the currently preferred configuration for the load 26. The transistors 31 and 33 are tied together using a connection 37. In FIG. 5C the connection 37 is pictorially located within the load 26. The current embodiment is not limited by this representation. A single OLED 37 is connected to the common connection 37.

FIGS. 6A to 6C present embodiments of the invention wherein the current mirror 24 and the load 26 are the same as the embodiment presented in FIG. 5C while various configurations of the switching circuitry are provided. The switching circuits presented in FIGS. 6A to 6C each have a feedback transistor 44 and a switch transistor 46.

In the circuit presented in FIG. 6A one terminal of the feedback transistor 44 and one terminal of the switch transistor 46 are connected to data line I-data. The second terminal of the feedback transistor 44 is connected to the drain of reference transistor 31 while the second terminal of

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the switch transistor **46** is connected to the gate of the reference and drive transistors **31** and **33**, respectively. Finally, the gate of the feedback transistor **44** and switch transistor **46** is connected to the select line V-sel1 and select line V-sel2, respectively.

In the embodiment presented in FIG. 6B the first terminal of the switch transistor **46** is connected to the data line I-data while the first terminal of the feedback transistor **44** is connected to the second terminal of the switch transistor **46** which is connected to the gate of the reference and drive transistors **31** and **33**, respectively. The second terminal of the feedback transistor **44** is connected to the drain of the reference transistor **31**. Finally, the gate of the feedback transistor **44** and switch transistor **46** is connected to the select line V-sel2 and select line V-sel1, respectively.

In the embodiment presented in FIG. 6C the first terminal of the switch transistor **46** is connected to the data line I-data while the first terminal of the feedback transistor **44** is connected to the second terminal of the switch transistor **46** which is connected to the drain of the reference transistor **31**. The second terminal of the feedback transistor **44** is connected to the gate of the reference and drive transistors **31** and **33**, respectively. Finally, the gate of the switch transistor **46** and feedback transistor **44** is connected to the select line V-sel1 and select line V-sel2, respectively.

The circuits that have been considered are embodiments of the circuit presented as a block diagram in FIG. 4. An alternative embodiment of the circuit architecture of FIG. 4 is presented in FIG. 7A. The organization of the switching circuit **22** and the current mirror **24** is the same as the embodiment presented in FIG. 4. In this embodiment the load **26** is arranged such that it is between the potential  $V_{DD}$  and the current mirror **24**. FIGS. 7B-7E present embodiments of the invention based on the block diagram of FIG. 7A. These embodiments implement the same circuit for the current mirror **24** while the configuration of the load **26** varies.

In the embodiment presented in FIG. 7B the load **26** includes light emitting diodes **40** and **42**. The diodes **40** and **42** are connected between the potential  $V_{DD}$  and the drain of reference transistor **31** and drive transistor **33**, respectively. The sources of the reference transistor **31** and the drive transistor **33** are connected to ground. The gates of the reference transistor **31** and the drive transistor **33** are tied together and connected to both the switching circuit **22** and a plate of the storage capacitor **25**. In the embodiment presented in FIG. 7C the light emitting diode **40** is connected to a potential  $V_c$  and the diode **42** is connected to the potential  $V_{DD}$ . The embodiments presented in FIGS. 7D and 7E differ from the embodiments of FIGS. 7B and 7C, respectively, in that the light emitting diode **40** is replaced with a transistor **47**. The gate of transistor **47** is connected to a third select line V-sel3, a first terminal is connected to a potential and a second terminal is connected to the source terminal of reference transistor **31**.

In the schematic diagram of FIGS. 5B, 7B, and 7C there are two OLEDs in each pixel. Such a double OLED structure is formed by partitioning the bottom electrode of the OLED of each pixel into two electrodes. Partitioning of the electrode provide for the formation of two OLEDs in each pixel. One of the OLEDs is connected to the drive transistor and the other is connected to the reference transistor. Therefore the load of reference and drive transistors is the same, resulting in a minimization of mismatches between these two transistors. It is noted that the ratio between the areas of the two OLEDs and the gain of the current mirror can be engineered to achieve desired circuit performance.

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According to an alternative embodiment of the invention the transistors can be any appropriate material for the fabrication of thin film transistors including polycrystalline silicon, polymer and organic materials. In particular this embodiment considers appropriate changes for including p-type TFTs that are relevant to persons skilled in the art.

According to another alternative embodiment of the invention the pixel drive circuits do not include the capacitor Cs.

According to another alternative embodiment of the invention the switching circuit **22** is appropriate for the use with a single select line.

According to another alternative embodiment of the invention the transistors of the pixel driver circuits may have more than one gate. In particular the transistors may be dual gate transistors.

According to another alternative embodiment of the invention there is more than one driver circuit for a given pixel. In particular there may be three pixel driver circuits as would be appropriate for pixels in an RGB or colour display.

The present invention has been described with regard to one or more embodiments. However, it will be apparent to persons skilled in the art that a number of variations and modifications can be made without departing from the scope of the invention as defined in the claims.

What is claimed is:

1. A pixel driver circuit for use in a display, comprising: switching circuitry for providing a reference current input, the switching circuitry including:

a switch transistor having a gate connected to a first select line, a first terminal connected to a data line, and

a feedback transistor having a gate connected to a second select line, a first terminal connected to a second terminal of the switch transistor;

a light emitting device having a first terminal and a second terminal, the second terminal being connected to a first potential; and

a current mirror for providing a drive current to the light emitting device based on the reference current, the current mirror including:

a drive transistor for conveying the drive current through the light emitting device and having a first node;

a reference transistor for receiving the reference current, the reference transistor having a gate connected to a gate of the drive transistor, the reference transistor having a drain terminal connected either to a second terminal of the feedback transistor or to a second terminal of the switch transistor, wherein the first terminal of the light emitting device is connected to the first node and to a source terminal of the reference transistor; and

a capacitor for storing a program voltage independent of a transistor threshold voltage, the program voltage settling on the capacitor while the reference current is conveyed through the reference transistor, the capacitor having a first terminal connected to both the gate of the drive transistor and the gate of the reference transistor, the capacitor having a second terminal connected to the first potential.

2. The pixel driver circuit according to claim 1, wherein the drain terminal of the reference transistor is connected to the second terminal of the feedback and a source terminal of the reference transistor is connected to a first terminal of the light emitting device.

3. The pixel driver circuit according to claim 2, wherein a second terminal of the light emitting device is connected to a ground potential.

4. The pixel driver circuit according to claim 1, wherein the drain terminal of the reference transistor is connected to the second terminal of the switch transistor and a source terminal of the reference transistor is connected to a first terminal of the light emitting device. 5

5. The pixel driver circuit according to claim 4, wherein a second terminal of the light emitting device is connected to a ground potential. 10

6. The pixel driver circuit according to claim 1, wherein the light emitting device is a light emitting diode.

7. The pixel driver circuit according to claim 6, wherein the first potential is a ground potential. 15

8. The pixel driver circuit according to claim 1, wherein the first potential is a ground potential.

9. The pixel driver circuit according to claim 1, wherein the reference and drive transistors are thin film transistors.

10. The pixel driver circuit according to claim 9, wherein the thin film transistors are amorphous silicon or polycrystalline silicon or organic. 20

11. The pixel driver circuit according to claim 10, wherein the reference and drive transistors are p-type.

12. The pixel driver circuit according to claim 1, wherein a first terminal of the drive transistor is connected to a supply voltage, and a second terminal of the drive transistor is connected to the light emitting device. 25

13. The pixel driver circuit according to claim 1, incorporated in an active matrix organic light emitting display (AMOLED). 30

\* \* \* \* \*